

ATTORNEY DOCKET NO.: MIT-160

INFORMATION DISCLOSURE STATEMENT

APPLICANT(S): Ariel et al.

:	SERIAL NO.: 10/823,083											
	•	FILING DATE: April 13, 2004 GROUP: 1745										
			U.S	. PATENT	DOCUM	ENTS				<del></del>		
EXAM. INIT.		DOCUMENT NUMBER     DATE NAME     CLASS SUB CLASS APPROPRIATE										
/RH/	A1	5,985,485	11/16/1999	Ovshins	nsky et al.							
/RH/	A2	6,242,132	06/05/2001	Neudecl	cer et al.							
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			FOREI	GN PATE	NT DOCU	JMENTS	3					
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/RH/	B1	01/73864	10/04/2001	wo				N		Y		
/RH/	B2	97/19481	05/29/1997	wo				N		Y		
/RH/	В3	01/80338	10/25/2001	WO				N		Υ		
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/RH/	Cı	Akridge and B	alkanski, <i>Solid</i>	State Microb	atteries, Plen	um press, (	1988).					
	C2	Antolini, "Prepp 1405-1411.	paration and Pr	operties of Li	-Co-O Compo	ounds," <u>J. c</u>	of the Euror	ean Ceran	nic Soc	<u>.</u> 18 (1998),		
	C3	Balkanski, et c 615-622.	Balkanski, et al., "Integrable Lithium Solid-State Microbatteries," <u>J. of Power Sources</u> , Vol. 26 (1989) pp. 615-622.									
	C4	Balkanski, "So Cells, 62 (200	olid-state micro 0), pp 21-35.	batteries for e	lectronics in	the 21st cen	tury," <u>Sola</u>	r Energy M	lateria	ls and Solar		
	C5	Barin, Thermo	chemical Data	Of Pure Subs	tances, 3rd e	dition, Wei	nheim, NY	, (1995).				
	C6	Bates et al, "T	hin-film rechar	geable lithiun	n batteries," <u>J</u>	of Power	Sources, 54	(1995), p	p 58-6	2.		
	C7	Bates et al, "T	hin-film lithiur	n and lithium	ion batteries,	" <u>Solid Sta</u>	te Ionics, 1	35 (2000),	pp 33	-45.		
V	C8	Bates et al., "I	Rechargeable T	hin-Film Lith	ium Microbat	teries," <u>Sol</u>	id State Te	chnology,	(1993)	pp 59-64.		
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	C10	Bonino <i>et al.</i> , (1995), pp 193		le lithium bat	teries based	on Li <sub>1+x</sub> V <sub>3</sub>	O <sub>8</sub> thin file	ms," <u>J. of</u>	Powe	er Sources, 56			
	C11	Boukamp <i>et al</i> (4), (1981), pp	., "All-Solid L	ithium Electro	des with Mix	ed-Conduc	tor Matrix,	" <u>J. of Ele</u>	etroch	em. Soc., 128,			
	C12.	Bourderau et a 81-82, (1999),	il., "Amorphou	is silicon as a	possible anod	e material i	or Li-ion b	atteries," ]	of Po	ower Sources,			
	C13	Brousse et al.,	"All oxide sol	id-state lithius	n-ion cells," ]	. of Power	Sources, 6	8 (1997), p	р 412	-415.			
	C14	Calister, Introd	duction to Mat	erials Science	and Enginee	ring, 3rd ed	lition, Wile	y, NY, (19	94).				
	C15	Campbell et al electrolyte," J.					and propyl	lene carbo	nate w	ithout added			
	C16	Chromik et al.	, "Thermodyna	amic and kine			actions in th	ne Cu-Si s	/stem,	" <u>J. of App.</u>			
	C17	Phys., 86 (8), (1999), pp 4273-4281.  Contestabile et al., "A laboratory-scale lithium-ion battery recycling process," J. of Power Sources, 92, (2001) pp 65-69.								rces, 92,			
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	C19	Dudney et al.,	"Sputtering of			paration of	electrolyte	thin films	." <u>Sol</u> i	d State Ionics,			
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		C22	Gao et al., "Al	loy Formation	in Nanostruct	ured Silicon,"	' Adv. Mat	_, 13, (11),	(2001), pp	816-8	19.	
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		C28	Julien et al., "(	Growth of LiM robatteries," M	n₂O₄ thin film	s by pulsed-la			eir electroc	hemic	al properties	
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		C30		nium alloy nega			r Sources,	81-82, (19	99), pp 13-	19.		
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